

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Dominik EISERT et al.

Serial No.: 10/523,551

Filed: October 18, 2005

For: GaN-Based Radiation-Emitting Thin-Layered
Semiconductor Component

Examiner: Nguyen, Joseph H.
Group Art: 2815

Mail Stop **Amendment**
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

SUPPLEMENTAL AMENDMENT

SIR:

Further to applicants' Amendment filed July 27, 2009 in response to the Office Action issued April 27, 2009, please amend the above-identified application as follows:

Amendments to the Claims begin on page 2 of this paper.

Remarks/Arguments begin on page 10 of this paper.